FEATURES 150 °C T_J operation

- · Center tap module
- · Very low forward voltage drop
- High frequency operation
- High power discrete
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- · New fully transfer-mold low profile, small footprint, high current package
- Designed and qualified for industrial level
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Note

This datasheet provides information about parts that are RoHS-compliant and/or parts that are non-RoHS-compliant. For example, parts with lead (Pb) terminations are not RoHS-compliant. Please see the information/tables in this datasheet for details.

DESCRIPTION

The center tap Schottky rectifier module has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Document Number: 94124

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL	CHARACTERISTICS	VALUES	UNITS				
I _{F(AV)}	Rectangular waveform	110	A				
V _{RRM}		30	V				
I _{FSM}	t _p = 5 μs sine	5100	А				
V _F	55 A _{pk} , T _J = 125 °C (per leg)	0.39	V				
TJ	Range	-55 to +150	°C				

VOLTAGE RATINGS							
PARAMETER	SYMBOL	VS-112CNQ030APbF	UNITS				
Maximum DC reverse voltage	V _R	30	V				
Maximum working peak reverse voltage	V _{RWM}		v				

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1

High Performance Schottky Rectifier New Generation 3, D-61 Package, 2 x 55 A

m	Anode Comm 1 catho	non Anode		
D-61-8-SM				
VS-112CNQ030ASLPbF	Bas comm catho 1 Anode 1	non		
PRODUCT SUMMAR	RY			
Package	D-61-8, D-61-8-SI	M, D-61-8-SL		
I _{F(AV)}	2 x 55	A		
V _R	30 V			
V _F at I _F	0.49 \	/		
I _{RM} max.	400 mA at ⁻	125 °C		
T _J max.	150 °C	C		
Diode variation	Common cathode			
E _{AS}	36 m.	J		

VS-112CNQ030APbF

ISHA



www.vishay.com

Base common cathode 95 33 Anode Anode Common 1 cathode 2

D-61-8

VS-112CNQ030ASMPbF



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ABSOLUTE MAXIMUM RATINGS							
PARAMETER		SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average per leg		levu a	50 % duty cycle at $T_{a} = 131$ °C	55	А		
See fig. 5	per device	I _{F(AV)}	50 % duty cycle at T_C = 131 °C, rectangular waveform		110	~	
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and	5100	A	
			10 ms sine or 6 ms rect. pulse	with rated V _{RRM}	880		
Non-repetitive avalanche energy per leg		E _{AS}	T _J = 25 °C, I _{AS} = 8 A, L = 1.12 mH		36	mJ	
Repetitive avalanche current per leg		I _{AR}	Current decaying linearly to zero in 1 μs Frequency limited by T_J maximum V_A = 1.5 x V_R typical		8	А	

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS		
		55 A	T.I = 25 °C	0.49	V		
Maximum forward voltage drop per leg	V _{FM} ⁽¹⁾	110 A	1j=25 C	0.57			
See fig. 1		55 A	T 105 %O	0.39			
		110 A	T _J = 125 °C	0.51			
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C		3.5	mA		
See fig. 2		T _J = 125 °C	V _R = Rated V _R	400			
Maximum junction capacitance per leg	CT	$V_{\rm R}$ = 5 V _{DC} , (test signal range 100 kHz to 1 MHz), 25 °C		5100	pF		
Typical series inductance per leg L _S		Measured lead to lead 5 mm from package body		5.5	nH		
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs		

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction and storage temperature range		T _J , T _{Stg}		-55 to +150	°C	
Maximum thermal resistanc junction to case per leg	Maximum thermal resistance, junction to case per leg		DC operation See fig. 4	0.5		
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	0.25	°C/W	
Typical thermal resistance, case to heatsink (D-61-8 only)		R _{thCS}	Mounting surface, smooth and greased0.30Device flatness < 5 mils			
				7.8	g	
Approximate weight	Approximate weight			0.28	oz.	
Mounting torque minimum				40 (35)	kgf ⋅ cm	
(D-61-8 only)	maximum			58 (50)	(lbf · in)	
Marking device			Case style D-61-8	112CN	Q030A	
			Case style D-61-8-SM	112CNQ	030ASM	
			Case style D-61-8-SL	112CNQ	030ASL	

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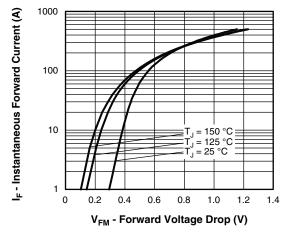
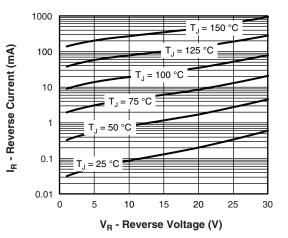
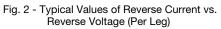


Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)





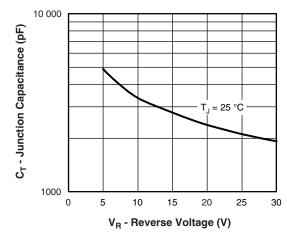


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

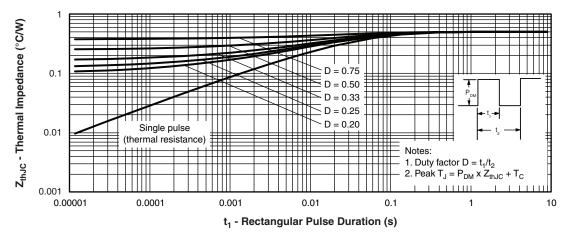
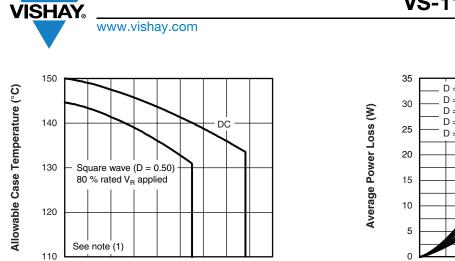
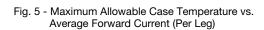


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

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I_{F(AV)} - Average Forward Current (A)

40 50 60 70 80 90

30

0 10 20

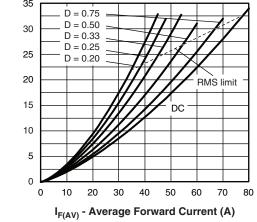


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

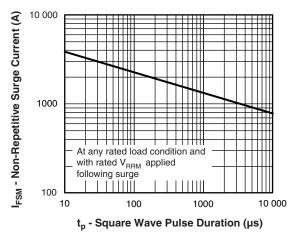


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

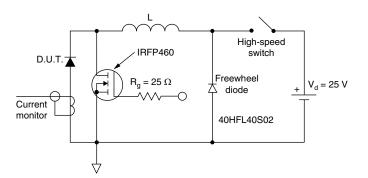


Fig. 8 - Unclamped Inductive Test Circuit

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

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VS-112CNQ030APbF Series





ORDERING INFORMATION TABLE

Device code	VS-	112	С	N	Q	030	Α	PbF
	1	2	3	4	5	6	7	8
	1 - 2 - 3 -	Cur	rent ratii uit confi	niconduc ng (110 iguratior	A) 1:	oduct		
	C = common cathode 4 - Package: N = D-61							
	 5 - Schottky "Q" series 6 - Voltage rating (030 = 30 V) 7 - Package style: 							
		• A = D-61-8 • ASM = D-61-8-SM • ASL = D-61-8-SL						
	8 -	 • None = standard production • PbF = lead (Pb)-free 						

Standard pack quantity: A = 10 pieces; ASM/ASL = 20 pieces

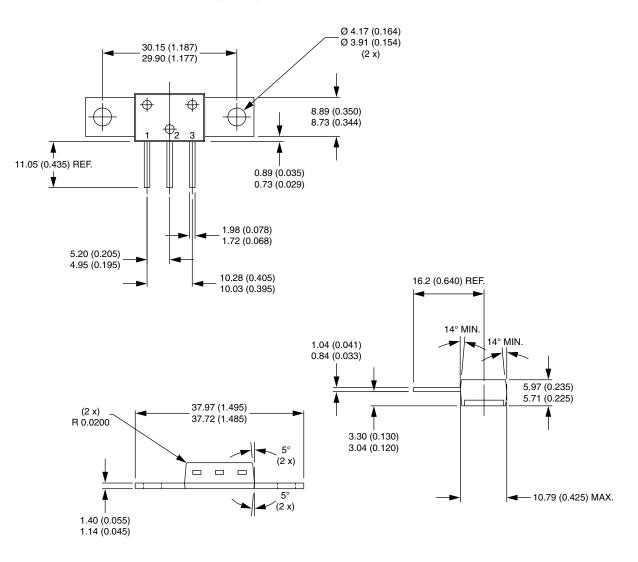
LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95354					
Part marking information	www.vishay.com/doc?95356				

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D-61-8, D-61-8-SM, D-61-8-SL

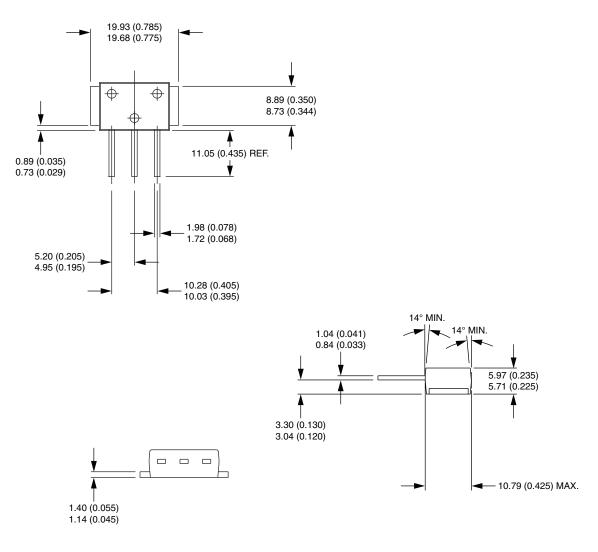
DIMENSIONS - D-61-8 in millimeters (inches)





DIMENSIONS - D-61-8-SM in millimeters (inches)

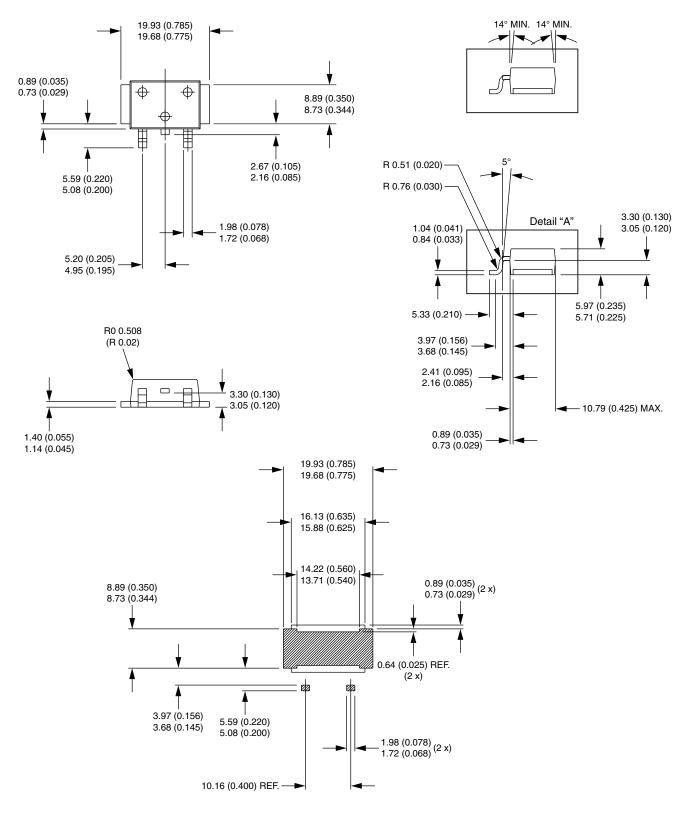
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DIMENSIONS - D-61-8-SL in millimeters (inches)

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